Refine Search

Search Results -

Terms	Documents
L30 or L28	35

Database:
US Pre-Grant Publication Full-Text Database
US Patents Full-Text Database
US OCR Full-Text Database
EPO Abstracts Database
JPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

Search: L31

Refine Search | Recall Text | Clear | Interrupt

Search History

DATE: Friday, May 12, 2006 Printable Copy Create Case

Set Name side by side	Query	Hit Count	Set Name result set
DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ			
L31	L30 or l28	35	L31
L30	l27 and L29	16	L30
L29	l25 or l22 or l20 or l15 or l12 or l1	20	L29
L28	l19 and L27	22	L28
L27	@ad<20021007	23060518	L27
L26	l8 and L23	2	L26
L25	l8 and L24	2	L25
L24	nerger.in.	322	L24
L23	hartmann.in.	9443	L23
L22	(interface device$1) same l3	1	L22
L21	l3 and l8	1	L21
L20	l16 and l10	2	L20
L19	l10 and L18	42	L19
L18	l8 and L17	380	L18

L17	365/$.ccls.	76961	L17
L16	714/$.ccls.	53789	L16
L15	l7 and L14	10	L15
L14	l8 and l10	376	L14
L13	l10 and L9	363	L13
L12	l10 and L11	8	L12
L11	(measur$6 near3 voltage$1) same (nominal voltage$1)	335	L11
L10	(measur$6 near3 voltage$1) and l8	376	L10
L9	(measur$5 near3 voltage$1) and l8	363	L9
L8	trim$5 same semiconductor$1	6418	L8
L7	(measurement current$1) and l5	285	L7
L6	l2 and L5	2	L6
L5	test$5 same (current source$1)	9086	L5
L4	l2 and L3	1	L4
L3	settable control element$1	48	L3
L2	(semiconductor$1 device$1) same (interface device$1)	143	L2
L1	trim$5 near3 (interface device$1)	3	L1

END OF SEARCH HISTORY